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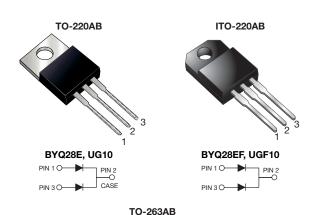
Vishay General Semiconductor

AUTOMOTIVE GRADE

RoHS

COMPLIANT

## **Dual Common Cathode Ultrafast Rectifier**





HEATSINK

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 5.0 A				
$V_{RRM}$	100 V to 200 V				
I <sub>FSM</sub>	55 A				
t <sub>rr</sub>	25 ns				
V <sub>F</sub>	0.895 V				
T <sub>J</sub> max.	150 °C				
Package	TO-220AB, ITO-220AB, TO-263AB				
Diode variations	Common cathode				

#### **FEATURES**

- Power pack
- Glass passivated chip junction
- · Ultrafast recovery times
- · Soft recovery characteristics
- · Low switching losses, high efficiency
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commerical grade Base P/NHE3 - RoHS-compliant, automotive grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix

meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	UG10BCT	UG10CCT	UG10DCT		
		BYQ28E-100	BYQ28E-150	BYQ28E-200	UNIT	
Maximum repetitive peak reverse voltage	$V_{RRM}$	100	150	200	V	
Working peak reverse voltage	$V_{RWM}$	100	150	200	V	
Maximum DC blocking voltage	$V_{DC}$	100	150	200	V	
Maximum average forward rectified current at T = 100 °C	- I <sub>F(AV)</sub>	10			Α	
Maximum average forward rectified current at $T_C = 100 ^{\circ}\text{C}$ per diode		5.0				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	55			Α	
Non-repetitive peak reverse current per diode at $t_p = 100 \mu s$	I <sub>RSM</sub>	0.2			Α	
Electrostatic discharge capacitor voltage, human body model: C = 250 pF, R = 1.5 k $\Omega$	V <sub>C</sub>	8			kV	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 40 to + 150			°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	$V_{AC}$	1500			V	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage per diode	I <sub>F</sub> = 10 A	T <sub>.I</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	1.25	V	
	Ι _ 5 Λ	1J = 25 C		1.10		
	I <sub>F</sub> = 5 A	T <sub>J</sub> = 150 °C		0.895		
Maximum reverse current per diode at		T <sub>J</sub> = 25 °C	1	10	μА	
working peak reverse voltage		T <sub>J</sub> = 100 °C	I <sub>R</sub>	200		
Maximum reverse recovery time per diode	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		t <sub>rr</sub>	25	ns	
Maximum reverse recovery time per diode	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>rr</sub> = 0.25 A		t <sub>rr</sub>	20	ns	
Maximum stored charge per diode	$I_F = 2 \text{ A}$ , $dI/dt = 20 \text{ A/}\mu\text{s}$ , $V_R = 30 \text{ V}$ , $I_{rr} = 0.1 I_{RM}$		Q <sub>rr</sub>	9	nC	

#### Note

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	UG10	UGF10	UGB10	UNIT	
		BYQ28E	BYQ28EF	BYQ28EB	UNII	
Typical thermal resistance per diode, junction to ambient	$R_{\theta JA}$	50	55	50	50 °C/W	
Typical thermal resistance per diode, junction to case	$R_{\theta JC}$	4.5	6.7	4.8	- ·C/w	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	BYQ28E-200-E3/45	1.80	45	50/tube	Tube		
ITO-220AB	BYQ28EF-200-E3/45	1.95	45	50/tube	Tube		
TO-263AB	BYQ28EB-200-E3/45	1.77	45	50/tube	Tube		
TO-263AB	BYQ28EB-200-E3/81	1.77	81	800/reel	Tape and reel		
TO-220AB	BYQ28E-200HE3/45 (1)	1.80	45	50/tube	Tube		
ITO-220AB	BYQ28EF-200HE3/45 (1)	1.95	45	50/tube	Tube		
TO-263AB	BYQ28EB-200HE3/45 (1)	1.77	45	50/tube	Tube		
TO-263AB	BYQ28EB-200HE3/81 (1)	1.77	81	800/reel	Tape and reel		

#### Note

<sup>(1)</sup> Automotive grade



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## **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

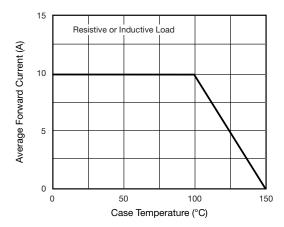


Fig. 1 - Forward Current Derating Curve

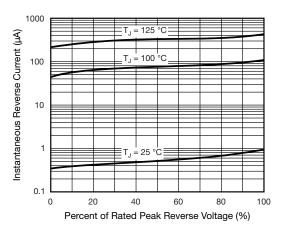


Fig. 4 - Typical Reverse Characteristics Per Diode

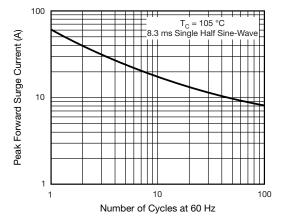


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

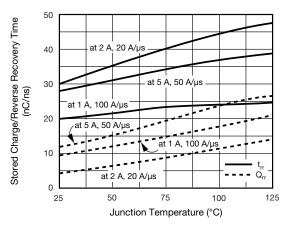


Fig. 5 - Reverse Switching Characteristics Per Diode

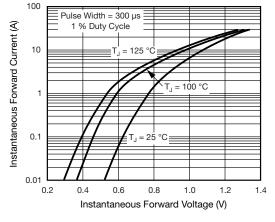


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

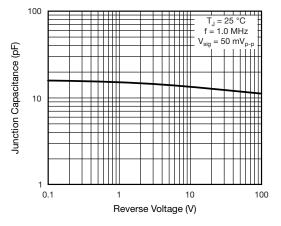


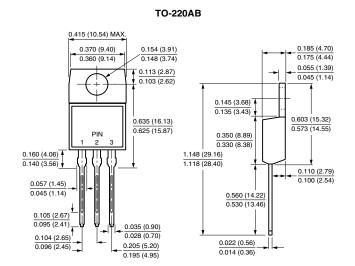
Fig. 6 - Typical Junction Capacitance Per Diode

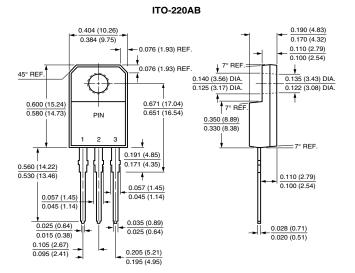


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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





#### 0.411 (10.45) 0.380 (9.65) 0.245 (6.22) MIN. 0.360 (9.14) 0.360 (9.14) 0.360 (9.14) 0.360 (9.14)

0.591 (15.00)

0.205 (5.20)

Κ

0.037 (0.940)

0.027 (0.686)

0.105 (2.67)

0.095 (2.41)

TO-263AB

# 0.42 (10.66) MIN. 0.33 (8.38) MIN. 0.670 (17.02) 0.591 (15.00) 0.15 (3.81) MIN. 0.08 (2.032) MIN.

0.095 (2.41)

0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.090 (2.29)

0.021 (0.53)

0.014 (0.36)

0.140 (3.56)

0.110 (2.79)



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